

## GaAs HEMT MMIC DRIVER AMPLIFIER, 17.5 - 41.0 GHz

### **Typical Applications**

This HMC-AUH256 is ideal for:

- · Point-to-Point Radios
- · Point-to-Multi-Point Radios
- VSAT
- SATCOM

#### **Features**

Gain: 21 dB

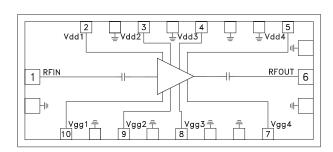
P1dB Output Power: +20 dBm

Wideband Performance: 17.5 to 40 GHz

Supply Voltage: +5V @ 295 mA

Small Chip Size: 2.1 x 0.92 x 0.1 mm

### **Functional Diagram**



### **General Description**

The HMC-AUH256 is a GaAs MMIC HEMT four stage Driver Amplifier which covers the frequency range of 17.5 to 40 GHz. The chip can easily be integrated into Multi-Chip-Modules (MCMs) due to its small (1.93 mm²) size. The HMC-AUH256 offers 21 dB of gain and +20 dBm output power at 1 dB compression from a bias supply of +5V @ 295 mA. The HMC-AUH256 may also be used as a frequency doubler. Detail bias condition to achieve doubler operation.

### Electrical Specifications [1], $T_A = +25$ °C Vdd1 = Vdd2 = Vdd3 = Vdd4 = 5V, Idd1 + Idd2 + Idd3 + Idd4 = 295mA[2]

Parameter		Min.	Тур.	Max.	Units
Frequency Range			17.5 - 41		GHz
Gain			21		dB
Input Return Loss			8		dB
Output Return Loss	20 - 30 GHz 30 - 45 GHz		15 8		dB dB
Output Power for 1 dB Compression			20		dBm
Saturated Output Power			23		dBm
Output IP3		·	27		dBm
Supply Current (Idd1 + Idd2 + Idd3 + Idd4)		·	295		mA

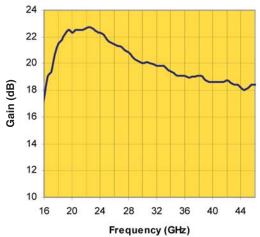
<sup>[1]</sup> Unless otherwise indicated, all measurements are from probed die

<sup>[2]</sup> Adjust Vgg1 = Vgg2 = Vgg3 = Vgg4 between -1V to +0.3V (Typ. -0.3V) to achieve Idd1 = 50 mA, Idd2 = 50 mA, Idd3 = 75 mA, Idd4 = 120 mA

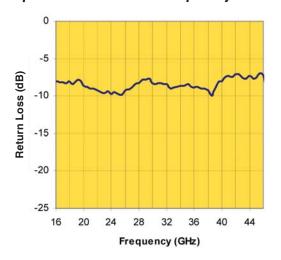


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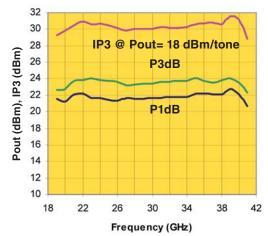
### Linear Gain vs. Frequency



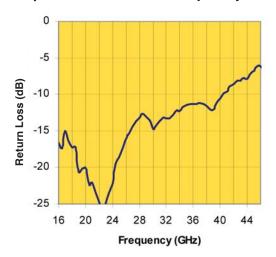
### Input Return Loss vs. Frequency



### Fixtured Pout vs. Frequency



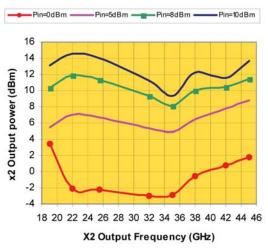
**Output Return Loss vs. Frequency** 



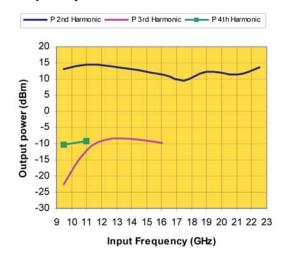


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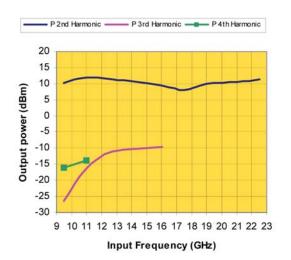
### x2 Pout vs. Frequency (vs Pad)



# Fixtured Pout vs. Frequency @ Pin= 10 dBm



## Fixtured Pout vs. Frequency @ Pin= 8 dBm



### **Absolute Maximum Ratings**

Drain Bias Voltage	+5.5 Vdc
RF Input Power	15 dBm
Drain Bias Current (Idd1, Idd2)	62 mA
Drain Bias Current (Idd3)	93 mA
Drain Bias Current (Idd4)	150 mA
Gate Bias Voltage	-1 to +0.3 Vdc
Channel Temperature	180 °C
Thermal Resistance (channel to die bottom)	77.5 °C/W
Storage Temperature	-65 to +150 °C

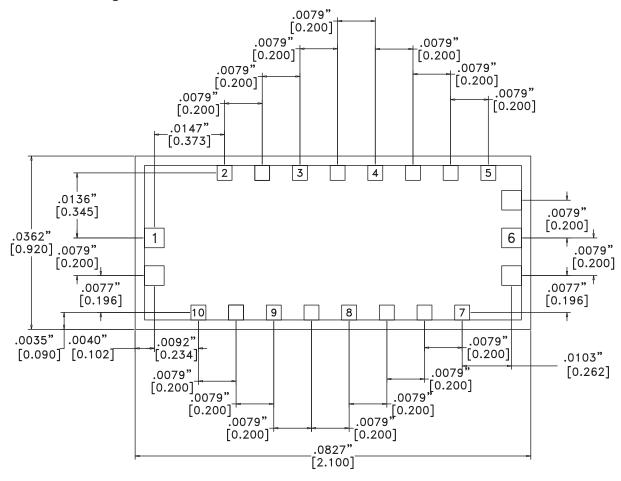


Note: Multiplier Performance Characteristics (Typical Performance at 25°C) Vd1= 2V, Vd2= Vd3= Vd4= 5V, Id1= 5mA, Id2+Id3+Id4= 245mA



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### **Outline Drawing**



#### NOTES:

- 1. ALL DIMENSIONS ARE IN INCHES [MM].
- 2. TYPICAL BOND PAD IS .004" SQUARE.
- 3. BACKSIDE METALLIZATION: GOLD.
- 4. BACKSIDE METAL IS GROUND.
- 5. BOND PAD METALLIZATION: GOLD.
- 6. CONNECTION NOT REQUIRED FOR UNLABELED BOND PADS.
- 7. OVERALL DIE SIZE ±.002"

## Die Packaging Information [1]

Standard	Alternate
GP-2 (Gel Pack)	[2]

[1] Refer to the "Packaging Information" section for die packaging dimensions.

[2] For alternate packaging information contact Hittite Microwave Corporation.



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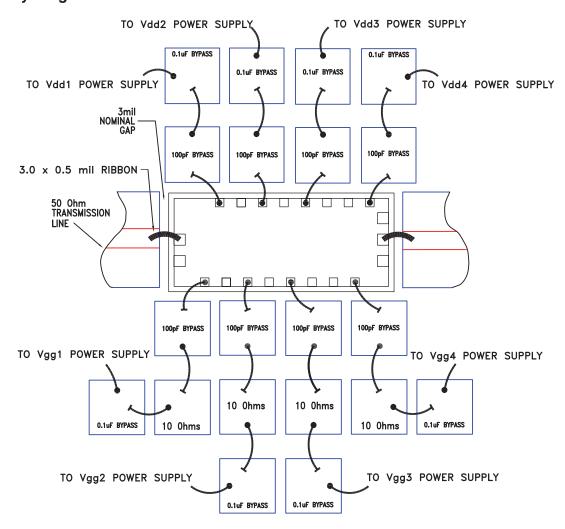
**Pad Descriptions** 

aa Booonphono					
Pad Number	Function	Pad Description	Interface Schematic		
1	RFIN	This pad is AC coupled and matched to 50 Ohms.	RFINO—  —		
2-5	Vdd1-4	Power supply voltage for amplifier. See Assembly Diagram for required external components.	Vdd1-4		
6	RFOUT	This pad is AC coupled and matched to 50 Ohms.	—   —○ RFOUT		
7 - 10	Vgg1-4	Gate control for amplifier. Please follow "MMIC Amplifier Biasing Procedure" application note. See assembly for required external components.	Vgg1-4		
Die Bottom	GND	Die Bottom must be connected to RF/DC ground.	○ GND		



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### **Assembly Diagram**



- Note 1: Bypass caps should be 100 pF (approximately) ceramic (single-layer) placed no farther than 30 mils from the amplifier.
- Note 2: Best performance obtained from use of <10 mil (long) by 3 by 0.5mil ribbons on input and output.
- Note 3: Vdd3 can be biased using on-chip pads Vdd3 or Vdd4

## **Mouser Electronics**

**Authorized Distributor** 

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Analog Devices Inc.:

HMC-AUH256 HMC-AUH256-SX